

# **Advanced materials processing with intelligent systems**

## **Dynamics of laser processes**

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Sergey Shevchik & Patrik Hoffmann

# UV- Excimer Laser Ablation

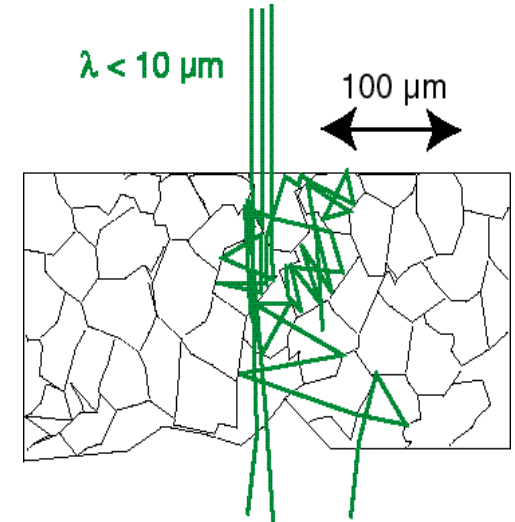
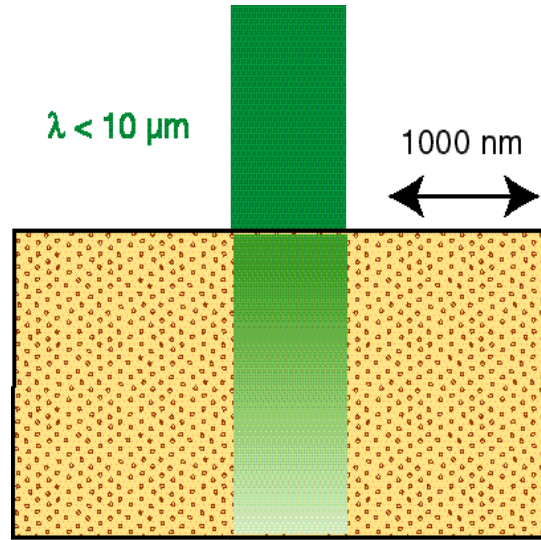
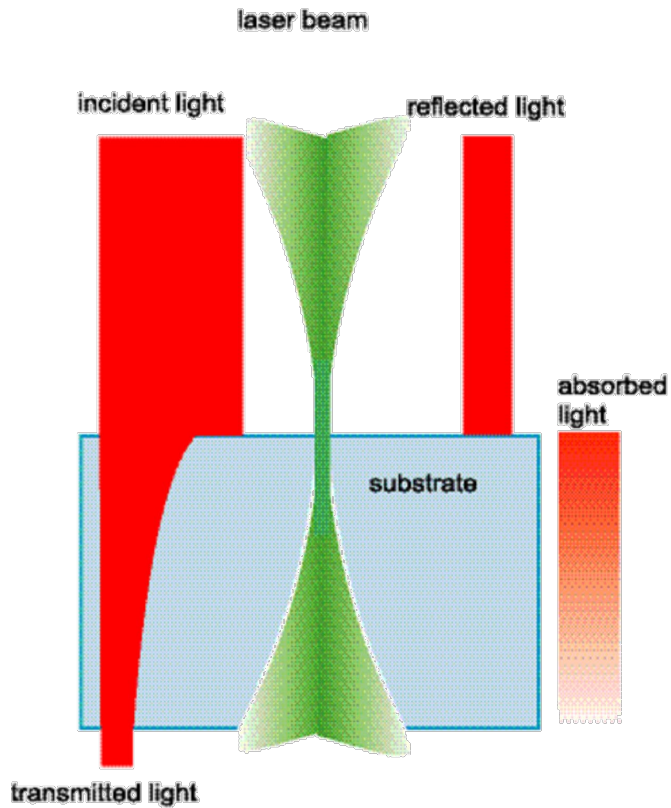
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- Model
- Influences
- Examples
- Applications

D. Bäuerle; Laser Processing and Chemistry,  
3<sup>rd</sup> Edititon, Springer Berlin, 2000

D. Bäuerle: Laser Processing and Chemistry,  
4<sup>th</sup> Edition, Springer Verlag, Berlin, Heidelberg 2011

# Laser light material interaction



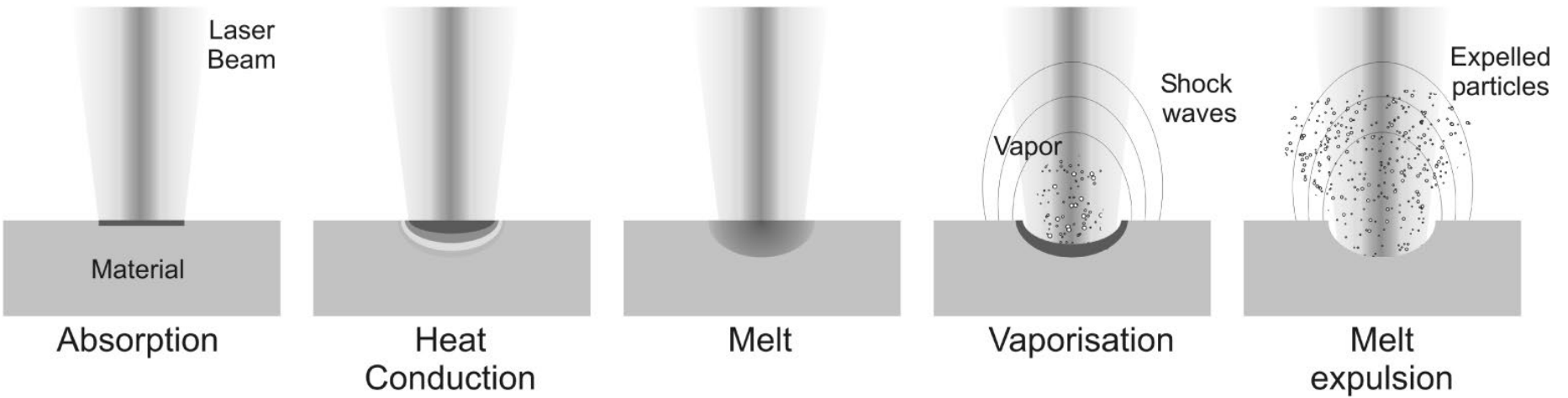
flat composit

micro- macro-  
structured

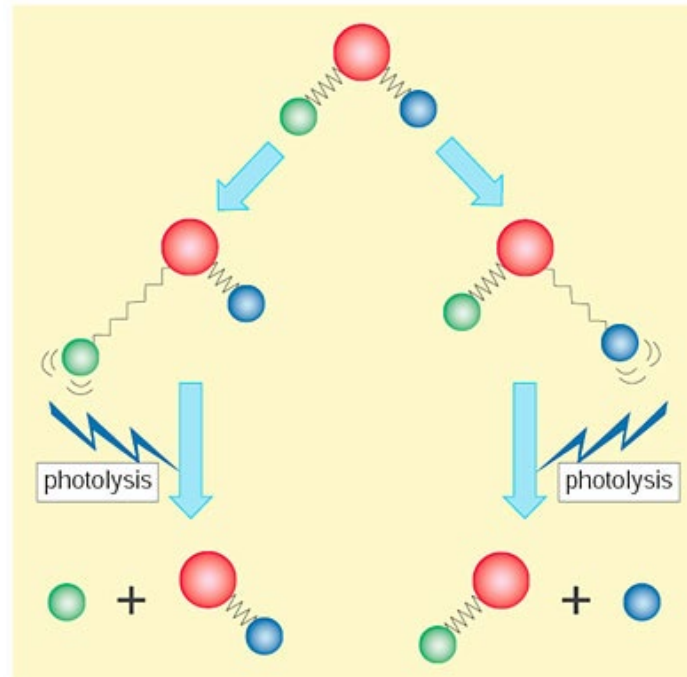
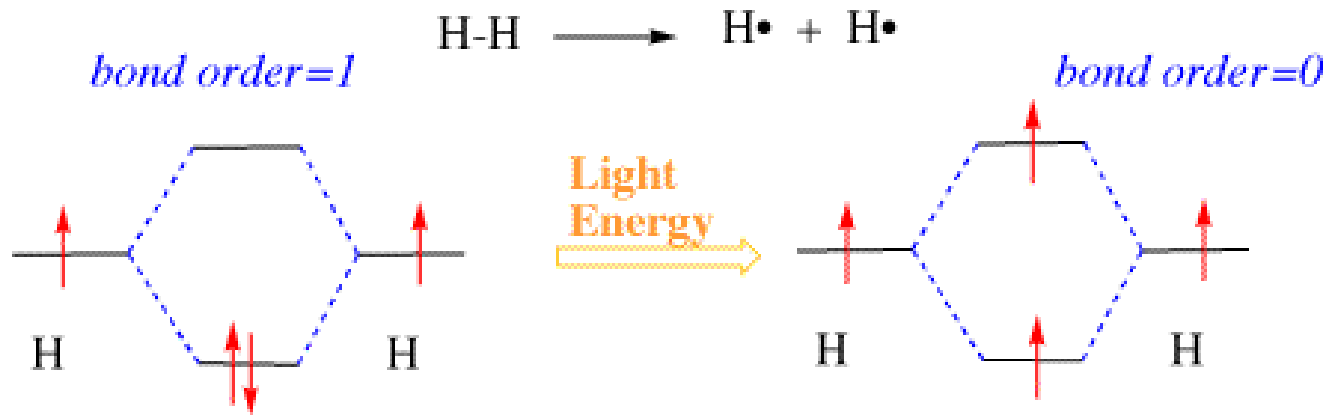
- Flat homogeneous

How is rough homogeneous ?

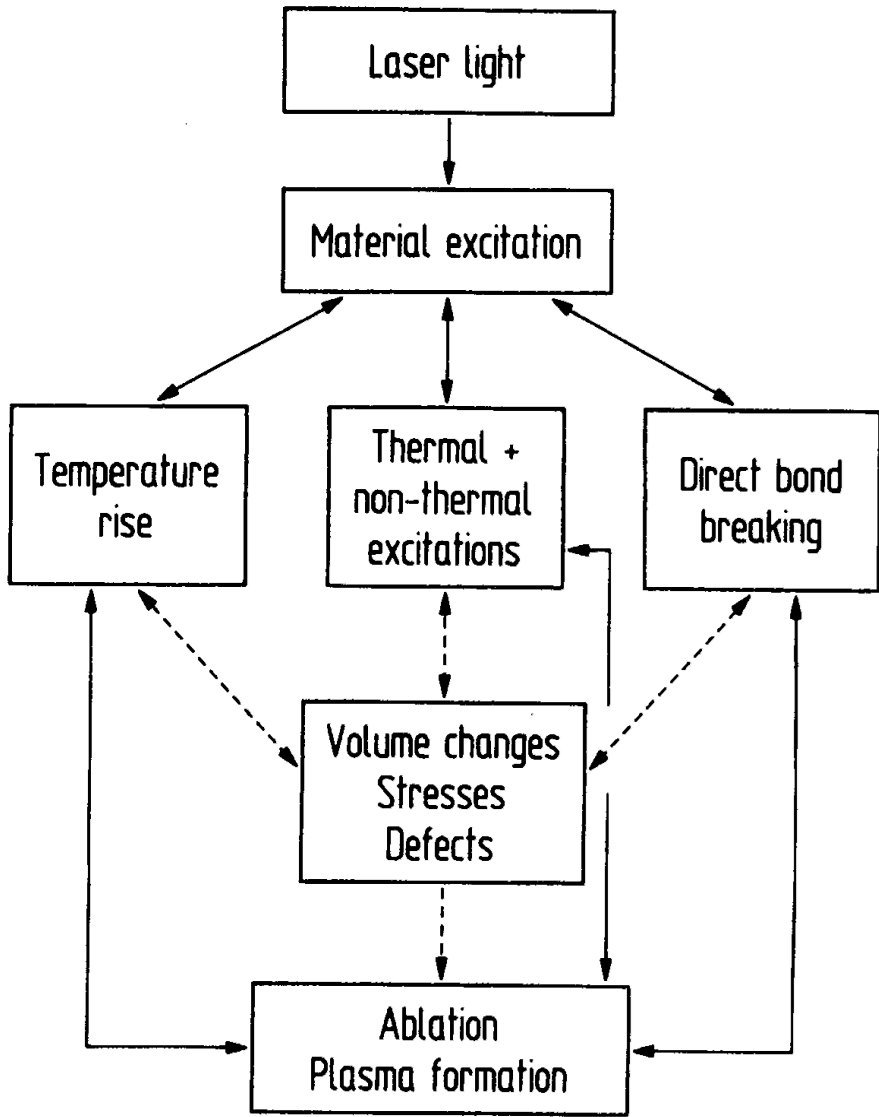
# Thermal Influence



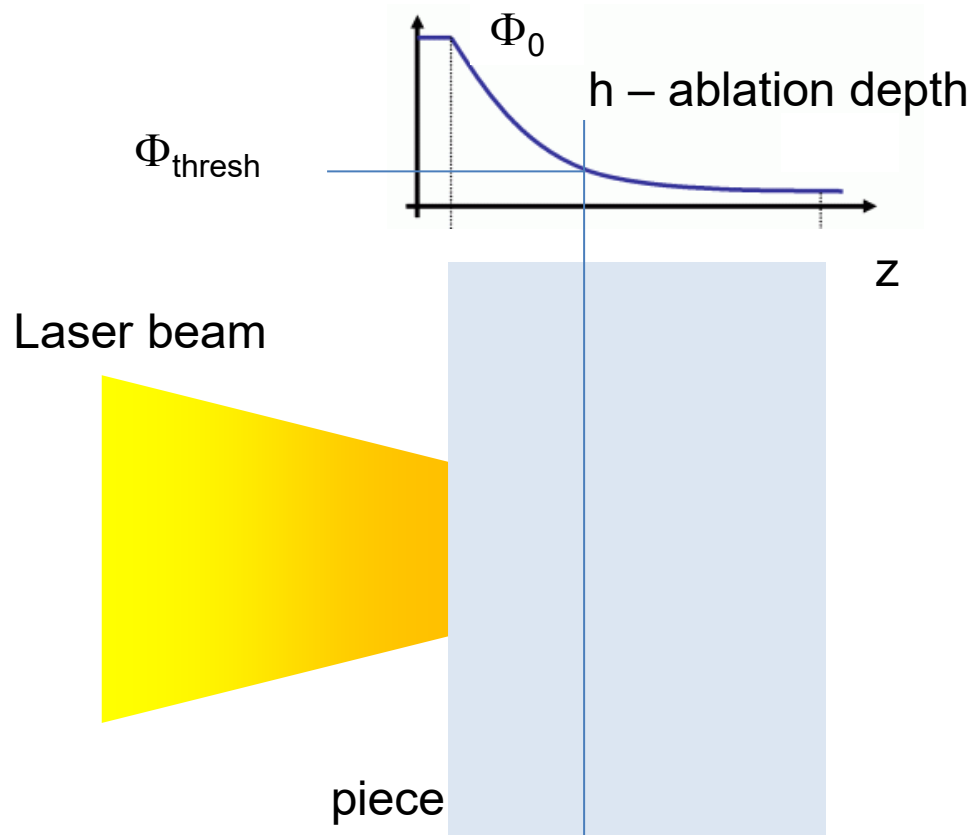
# Photolysis – Direct Bond Breaking



# Ablation model



# Ablation Depth



# Physical Model

$$\Phi(d) = \Phi_{\text{exp}}^{-\alpha_{\text{eff}} \cdot d}$$

Lambert-Beer's absorption law

$$\Phi_{\Delta h} = \Phi_{\text{thresh}} = \Phi_0^{-\alpha_{\text{eff}} \cdot \Delta h}$$

threshold fluence is still reached at  $\Delta h$  depth

$$\Delta h(\Phi) = l_{\alpha_{\text{eff}}} \ln \Phi - l_{\alpha_{\text{eff}}} \ln \Phi_{\text{thresh.}}$$

ablation rate vs. fluence dependance

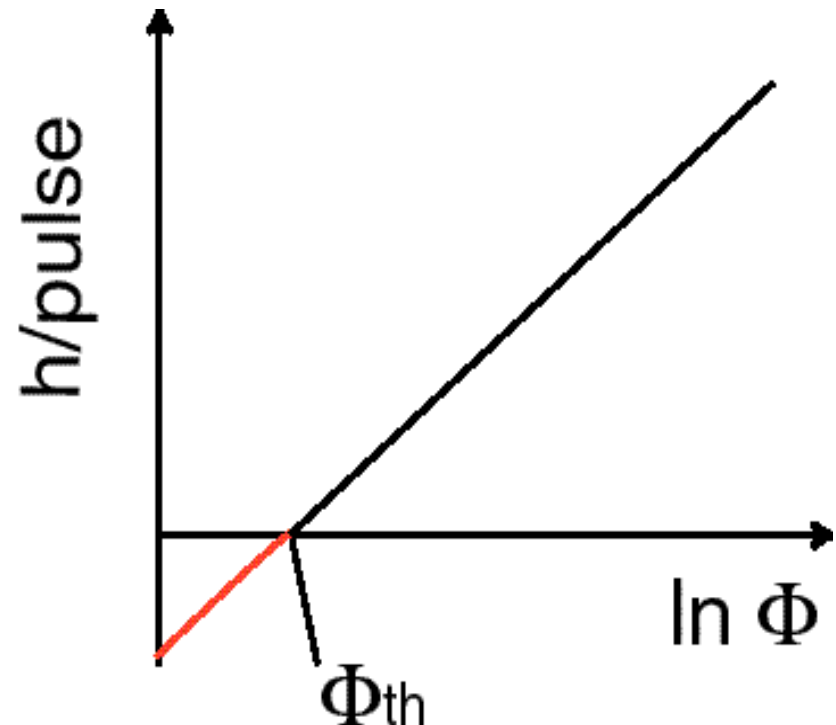
## Effective Absorption Coefficient

$$\alpha_{\text{eff}} = \alpha_0 + \sigma_D N_D + \alpha_i(N) + \alpha^{NL}$$

$\alpha_0$  = linear absorption coefficient

$\sigma_D$  = Dopant cross section

**Limits: no sense at extremely high laser powers, avalanche ionization**



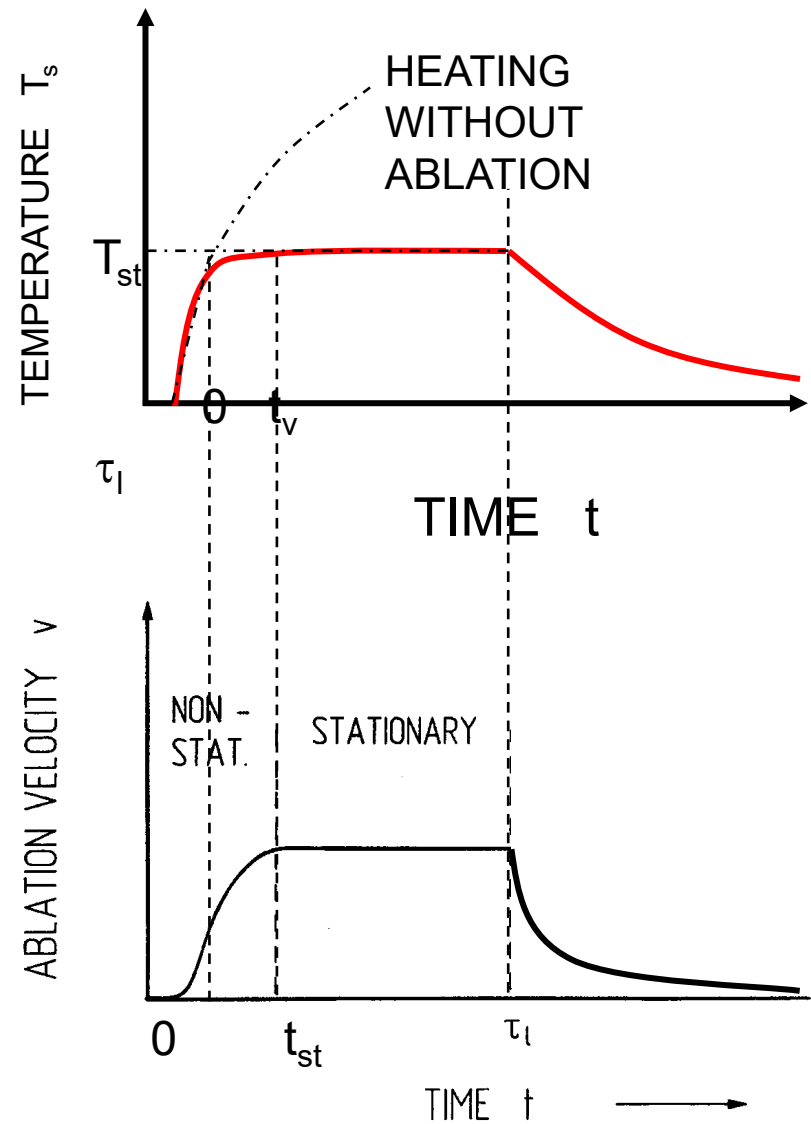
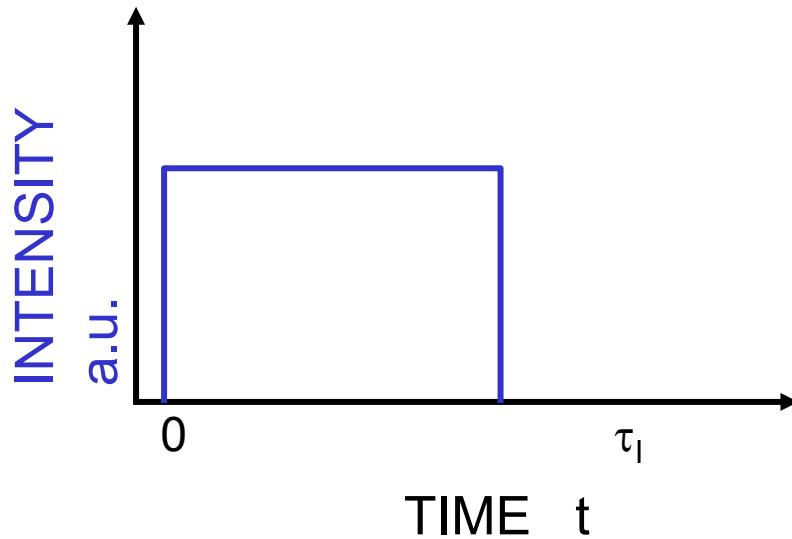
# Single Pulse Ablation

## Photothermal ablation

$\tau_T \ll \tau_{des}$  pure thermal ablation, IR, vis and many UV

### Assumptions:

- homogeneous irradiation
- $w \gg l_{th}; l_{\alpha}$
- no stress
- no T dependence



# Single pulse ablation

- Influence of pulse duration

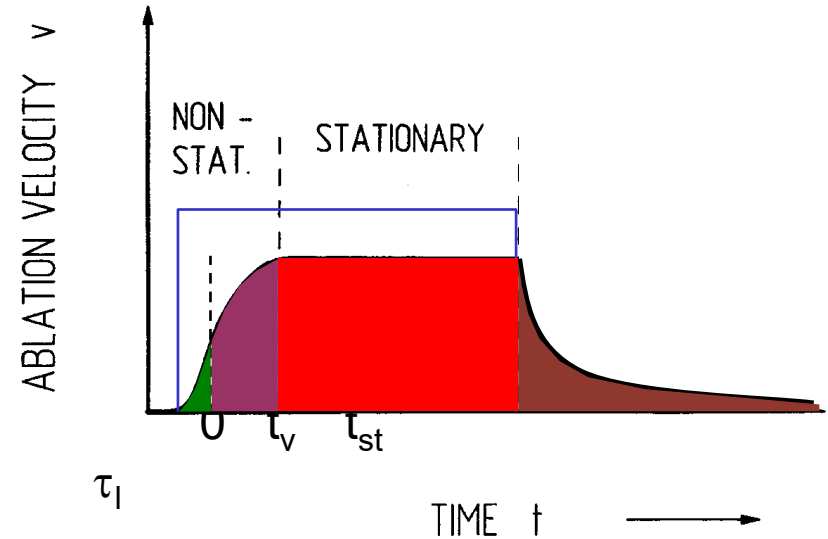
$$\Delta h = \int_0^{\infty} v(t) dt \approx \Delta h_1 + \Delta h_2 + \Delta h_3 + \Delta h_4$$

$$\Delta h_1 \equiv \Delta h_1(t \leq t_v)$$

$$\Delta h_2 \equiv \Delta h_2(t_v \leq t \leq t_{st})$$

$$\Delta h_3 \equiv \Delta h_3(t_{st} \leq t \leq \tau_l)$$

$$\Delta h_4 \equiv \Delta h_4(t \geq \tau_l)$$



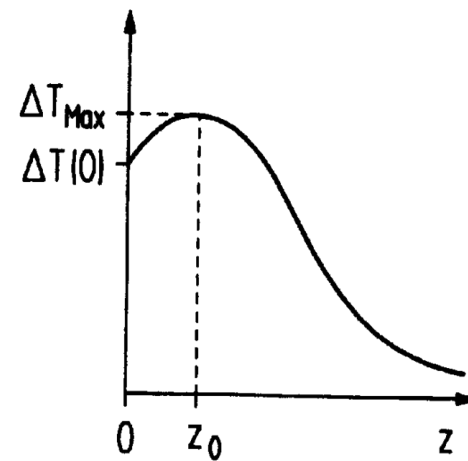
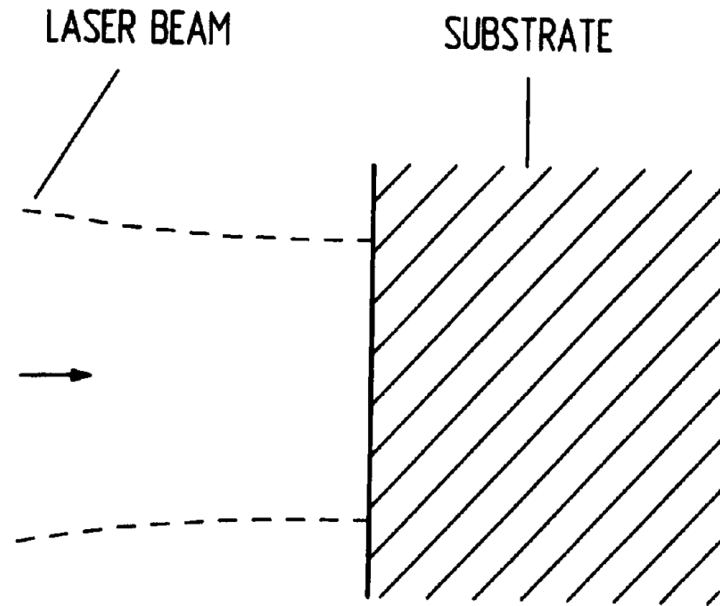
$\Delta h_1$  to be ignored in all cases

**fs, ps** ablation  $\Delta h_4$

**ns, ms** ablation  $\Delta h_3$

**ns** ablation  $\Delta h_2, \Delta h_3, \Delta h_4$

# Pulsed Laser Ablation



# Interaction 193 nm Excimer light with materials

- Optical penetration depth:

$$l_{\alpha} = \frac{1}{\alpha}$$

- Thermal penetration depth:

$$l_{th} = 2\sqrt{D\tau_l}$$

	$l_{\alpha}$	$l_{th}$
<b>Al</b>	<b>10 nm</b>	<b>2.80 <math>\mu\text{m}</math></b>
<b>Mo</b>	<b>&lt; 30 nm</b>	<b>2.04 <math>\mu\text{m}</math></b>
<b>SiO<sub>2</sub></b>	<b>3.3 m</b>	<b>270 nm</b>
<b>PET</b>	<b>30 nm</b>	<b>90 nm</b>

$\alpha$ : optical absorption coefficient  
[cm<sup>-1</sup>]

D: thermal diffusivity [cm<sup>2</sup> /s]

$\tau_l$ : pulse duration

# Pulsed Laser Ablation (PLA)

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- How much material is taken off per laser pulse ?

$$\Delta h \approx \max(l_{th}, l_{\alpha})$$

What are the physical steps ?

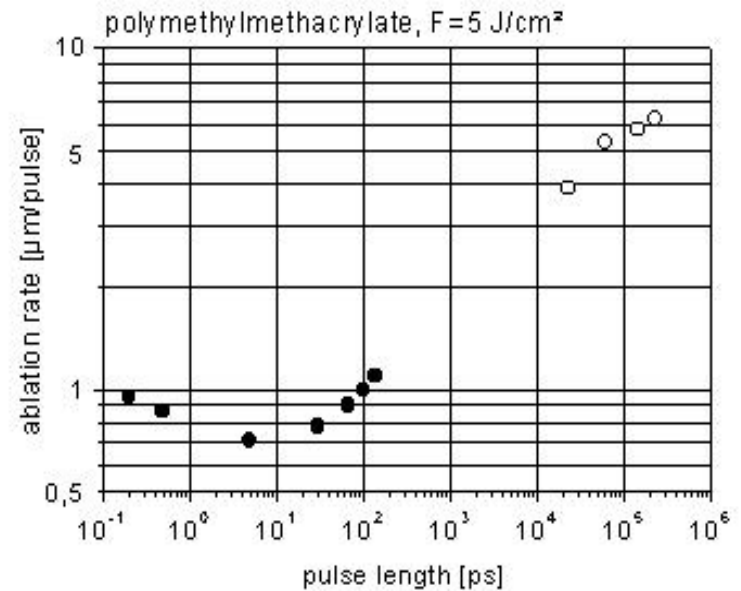
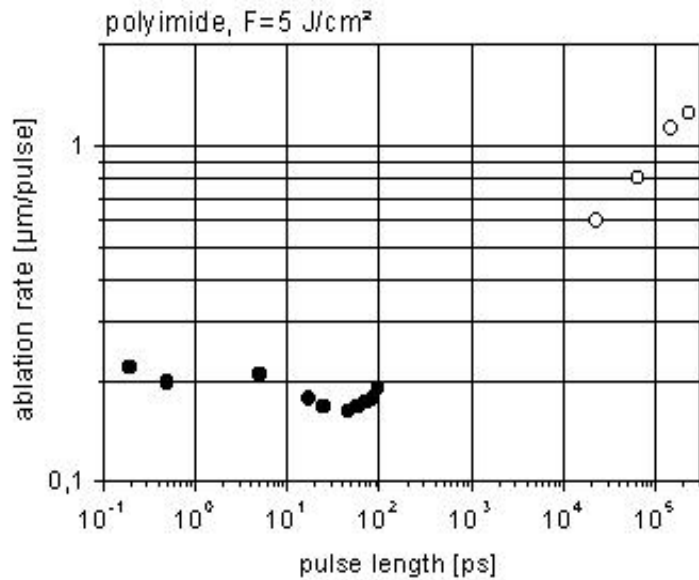
Optical absorption

Energy dissipation

Decomposition

Material removal

# Ablation rate dependance: Pulse duration



# Conclusions

## Ablation Process characteristics

threshold value for Laser light fluence  $\phi_{th}$

$$\phi_{th_{oxides}} = 0.5 - 2 \text{ [J/cm}^2\text{]}$$

$$\phi_{th_{polymers}} = 0.01 - 1 \text{ [J/cm}^2\text{]}$$

ablation depth per pulse :  $\Delta h \leq \max(l_T, l_\alpha)$

with

the heat penetration depth  $l_T$  :

$$l_T \approx 2\sqrt{D\tau_l}$$

including the laser pulse length  $\tau_l$

and the thermal diffusivity  $D = \kappa/(\rho c_p)$

$$D_{metals} = 0.1 - 2 \text{ [cm}^2\text{/s]}$$

$$D_{oxides} = 0.01 - 1 \text{ [cm}^2\text{/s]}$$

$$D_{polymers} = 0.001 - 0.01 \text{ [cm}^2\text{/s]}$$

the light penetration depth  $l_\alpha$  :

$$l_\alpha = \alpha^{-1}$$

# Is Cold Laser Processing possible ?

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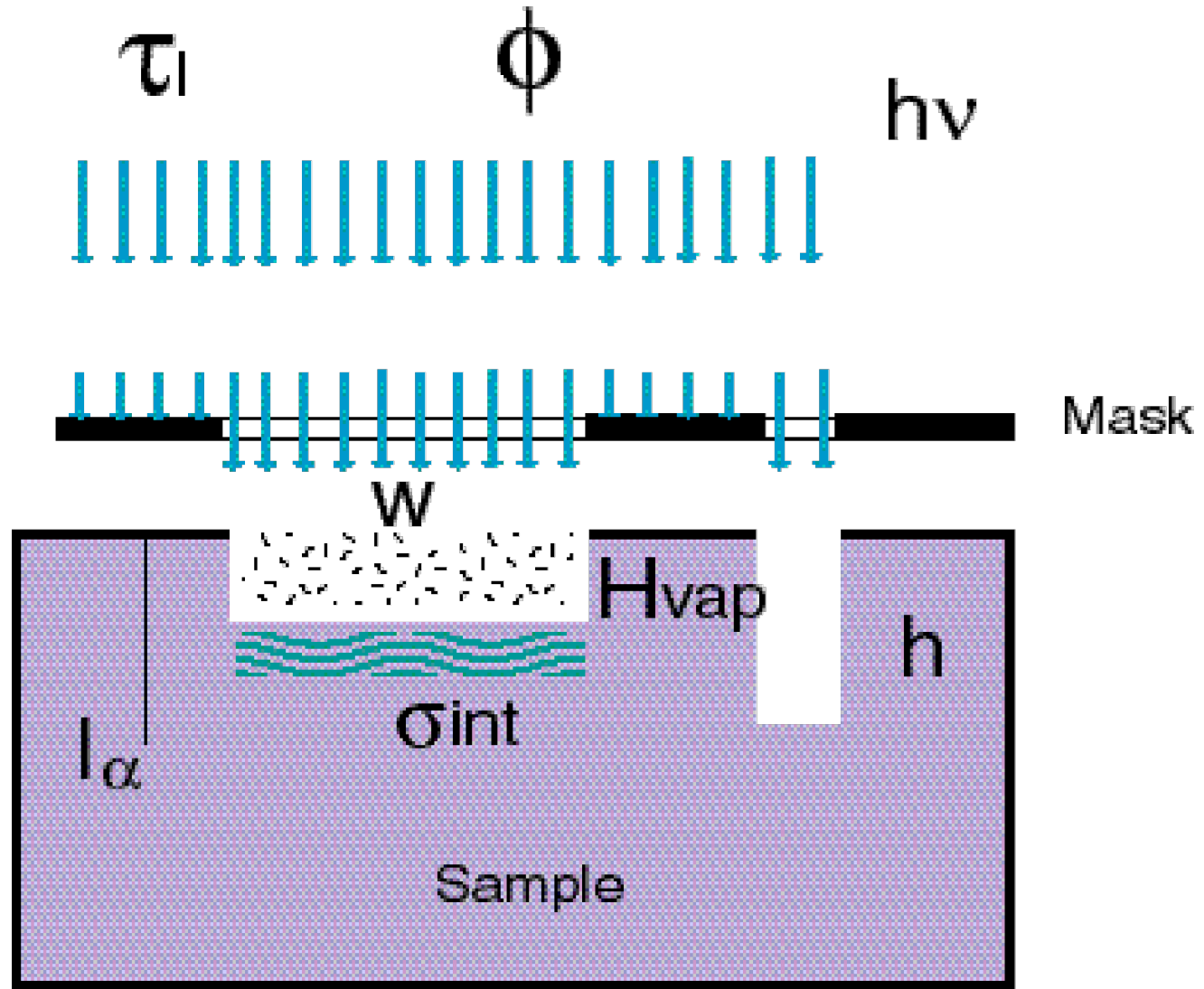
High vacuum molecule photon interactions:  
Excitation by absorption – thermal relaxation  
( $10^{-14} - 10^{-6}$  s) useful for isotope separation,  
polyatomic molecules, ( $10^{-13} - 10^{-11}$  s)

Generally in liquids and solids:

Excitation by absorption – thermal relaxation  $\tau_T$   
Metals & Semicond. (el-el)  $10^{-14}$ - $10^{-13}$  s ; (el-phon)  $10^{-12}$ - $10^{-6}$  s

Check thermal effects: The heat equation

# Ablation – complex phenomenon



# Excimer Laser model

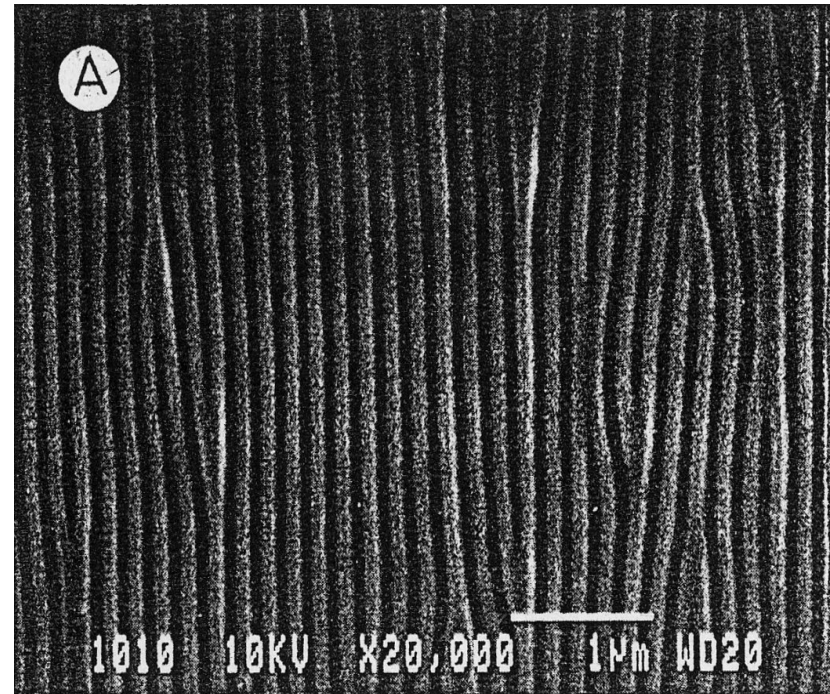
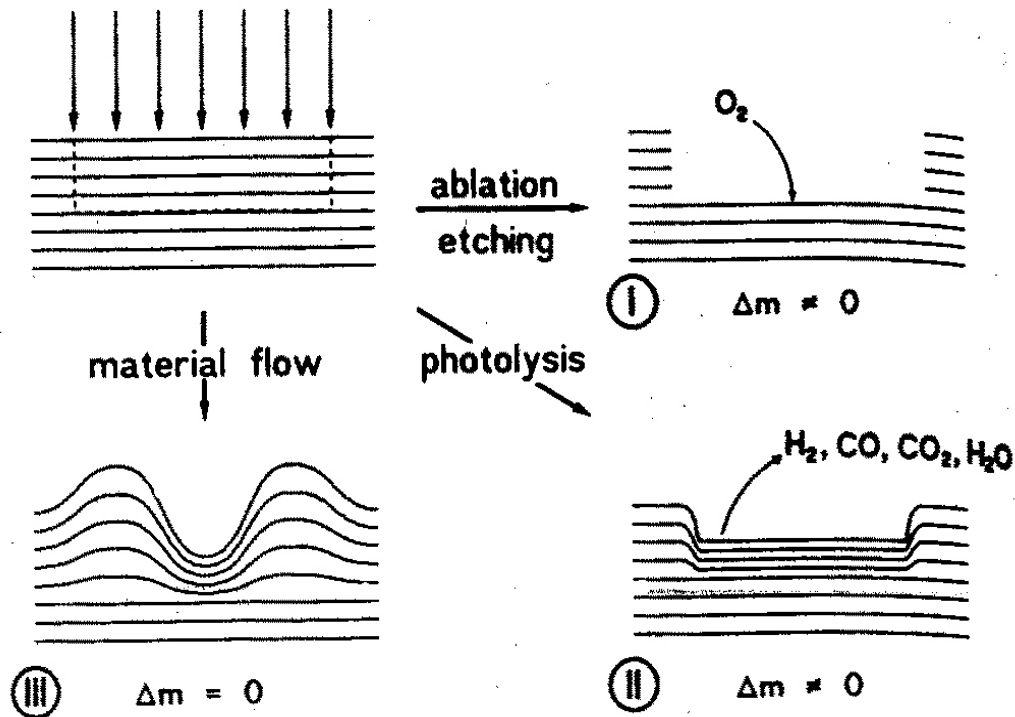
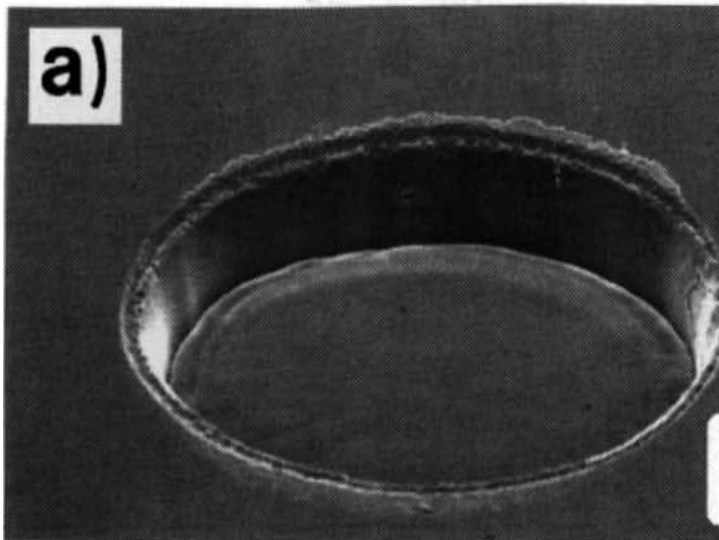
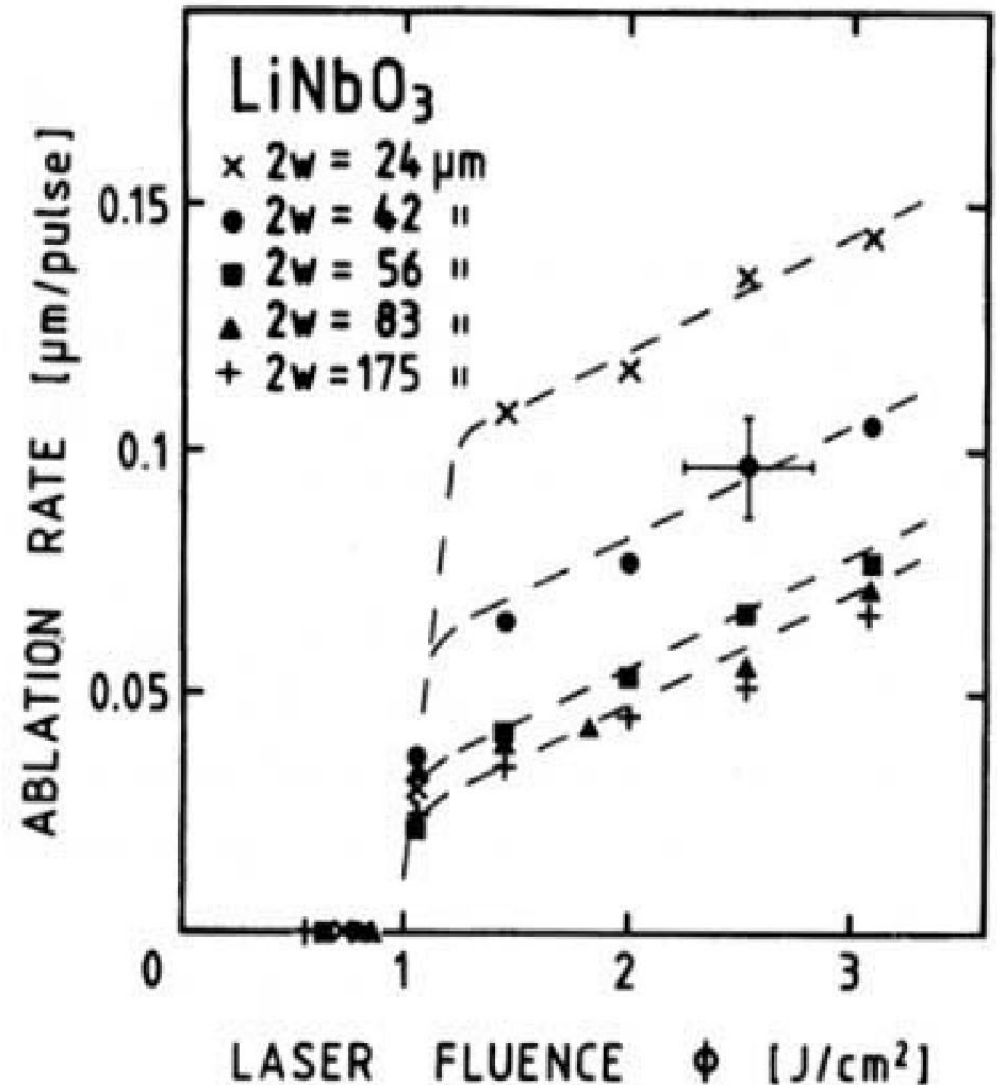


FIG. 13. Three models of photoactivated surface corrugation; (I) ablation or etching; (II) photolysis; (III) is material flow. Processes I and II are accompanied with mass decrease, even in vacuum, whereas III operates at constant mass.

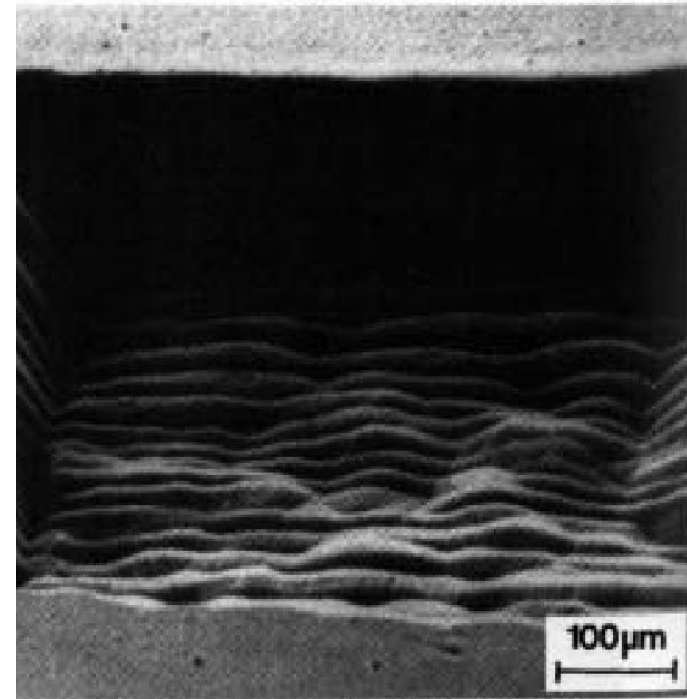
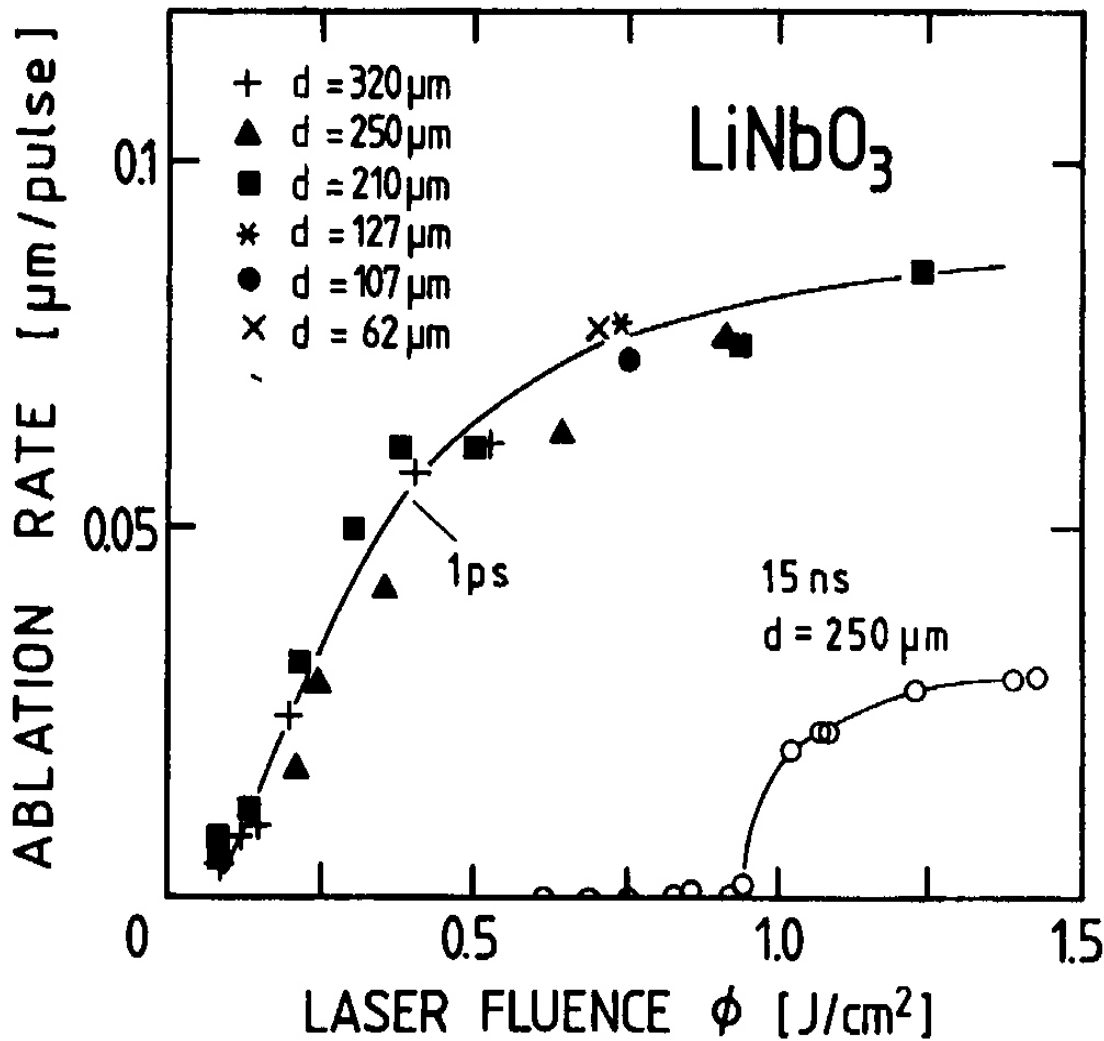
# Ceramics Ablation Examples



**Fig. 12.1.2a,b.** Projection patterning by ( $\lambda = 308 \text{ nm}$ ,  $\phi = 2.7 \text{ J/cm}^2$ ,  $2w = 175 \mu\text{m}$ )  $\text{YBa}_2\text{Cu}_3\text{O}_7$  film on (100)  $\text{SrTiO}_3$  sub [Heitz et al. 1990]

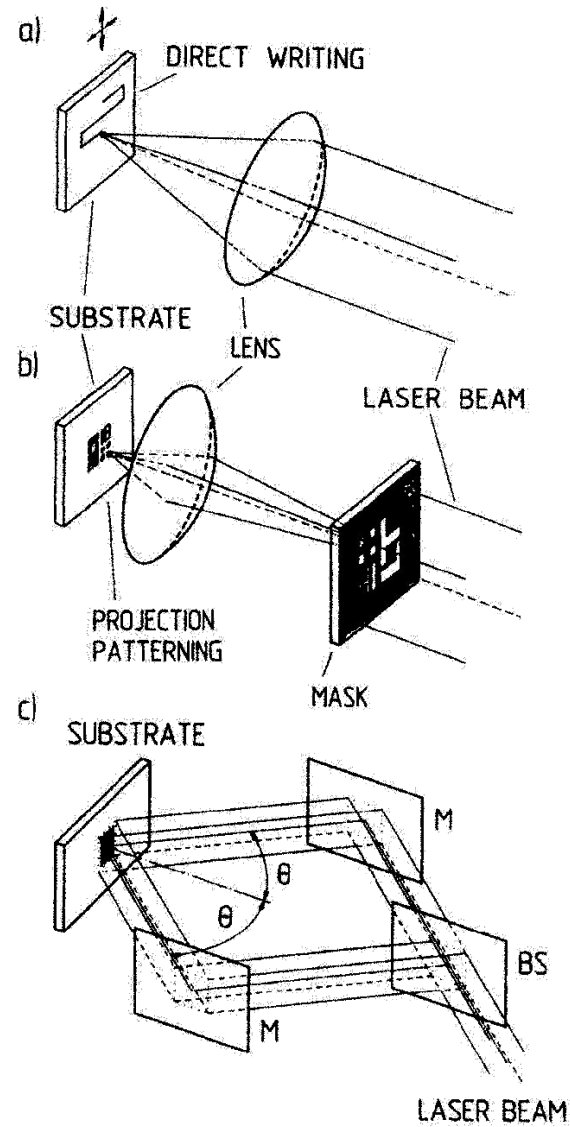


# Ablation Influences



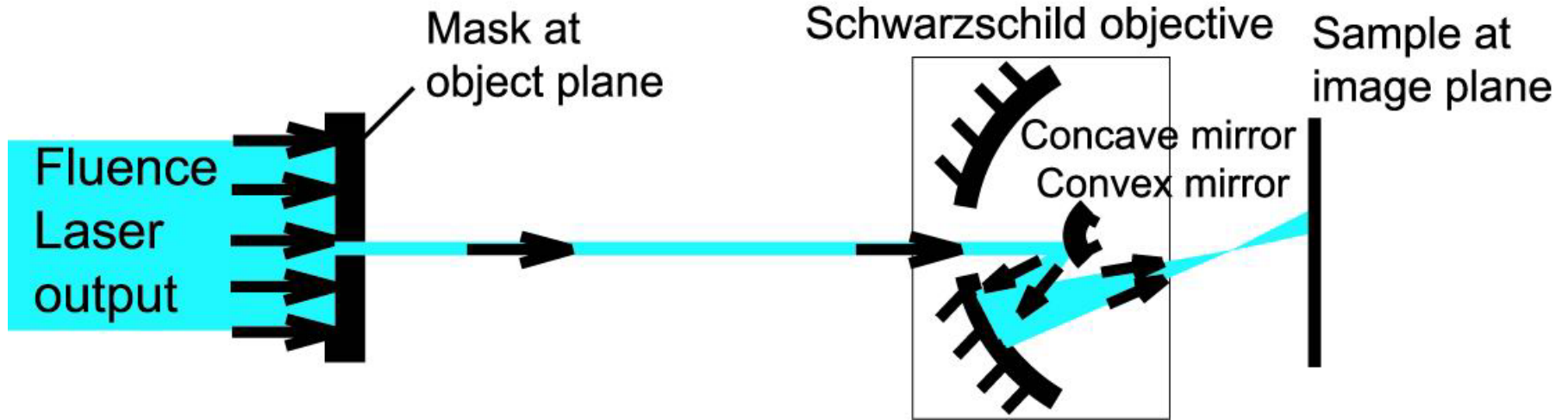
48 nm KrF-laser radiation. (a) Irradiation with ns pulses ( $\phi = 4.2 \text{ J}/\text{cm}^2$ ). An undefined crater is visible in the material. (b) Irradiation with fs pulses. The surface is relatively smooth and no cracks are observed.

# Method Based on Interference





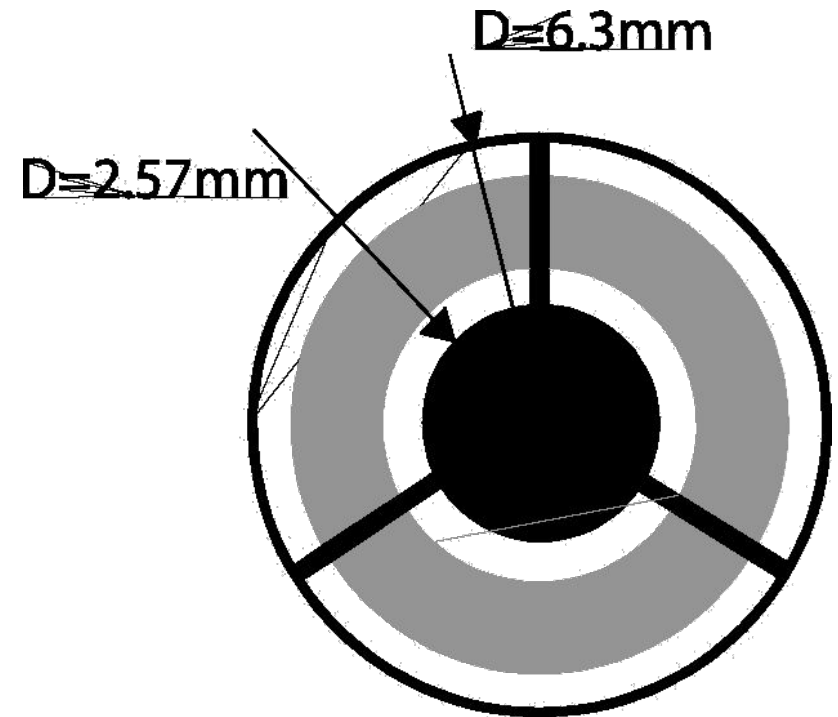
# Schwarzschild objective: Set-up



- ArF Excimer Laser pulsed at 20ns
- Fluence Laser output : 25-250 mJ/cm<sup>2</sup>
- Image magnification: 1/25
- Fluence gain : 45 x Fluence at Laser output

# Schwarzschild objective

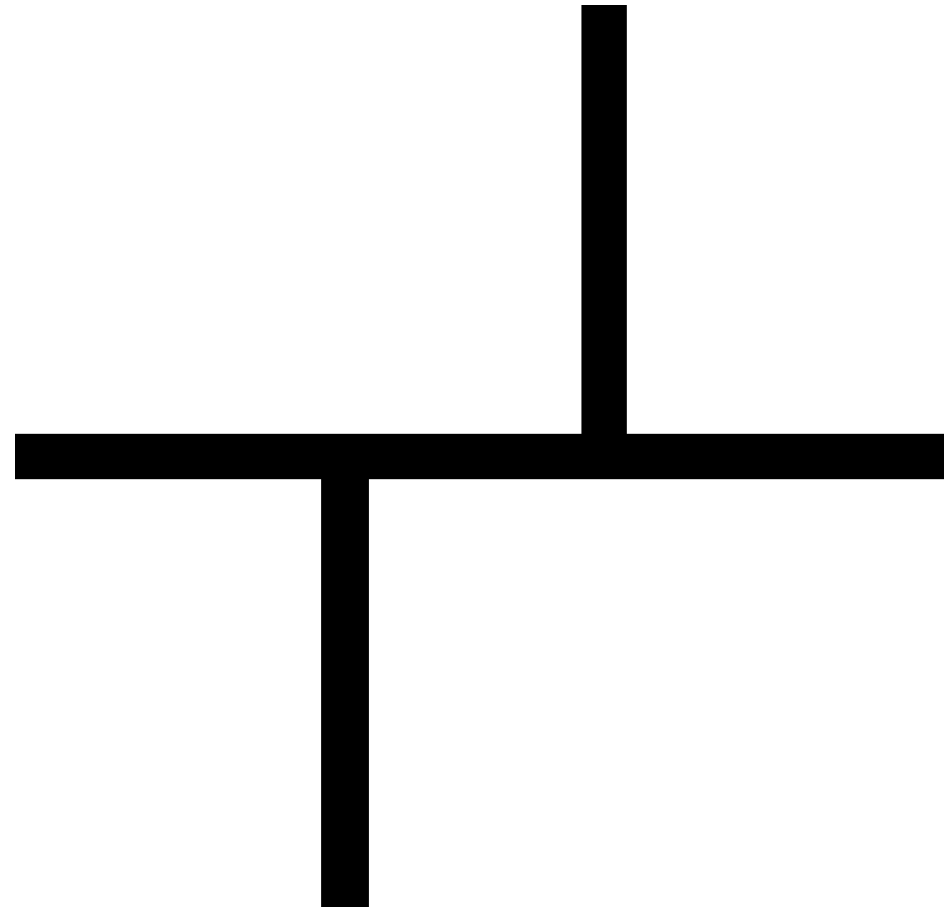
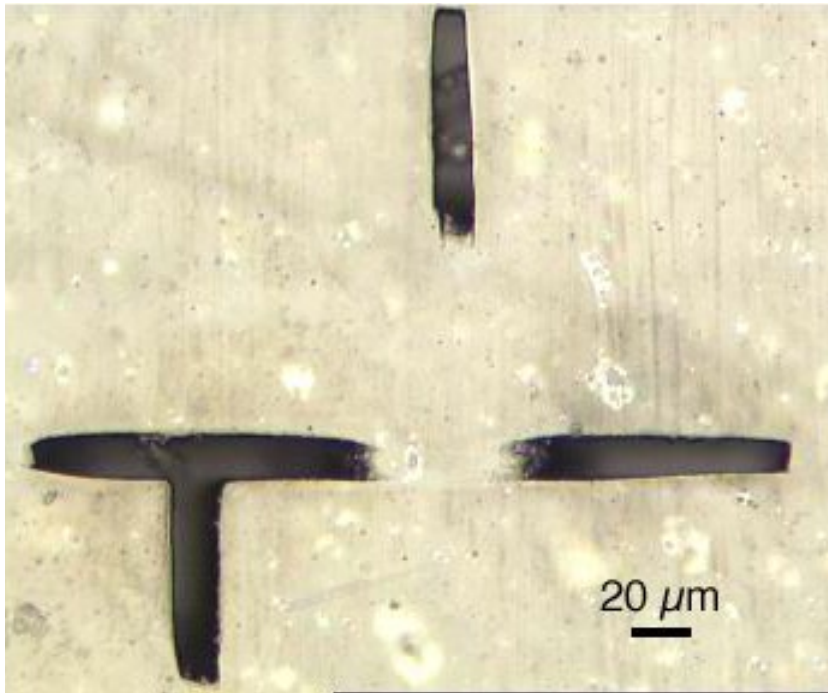
- Magnification 1/25
- Low aberrations, achromatic
- Numerical aperture :  $NA = 0.4$
- Central obscuring : 16.7%
- Mirror : coating for 193 nm
- maximum reflection  $R_{\max} = 0.5$



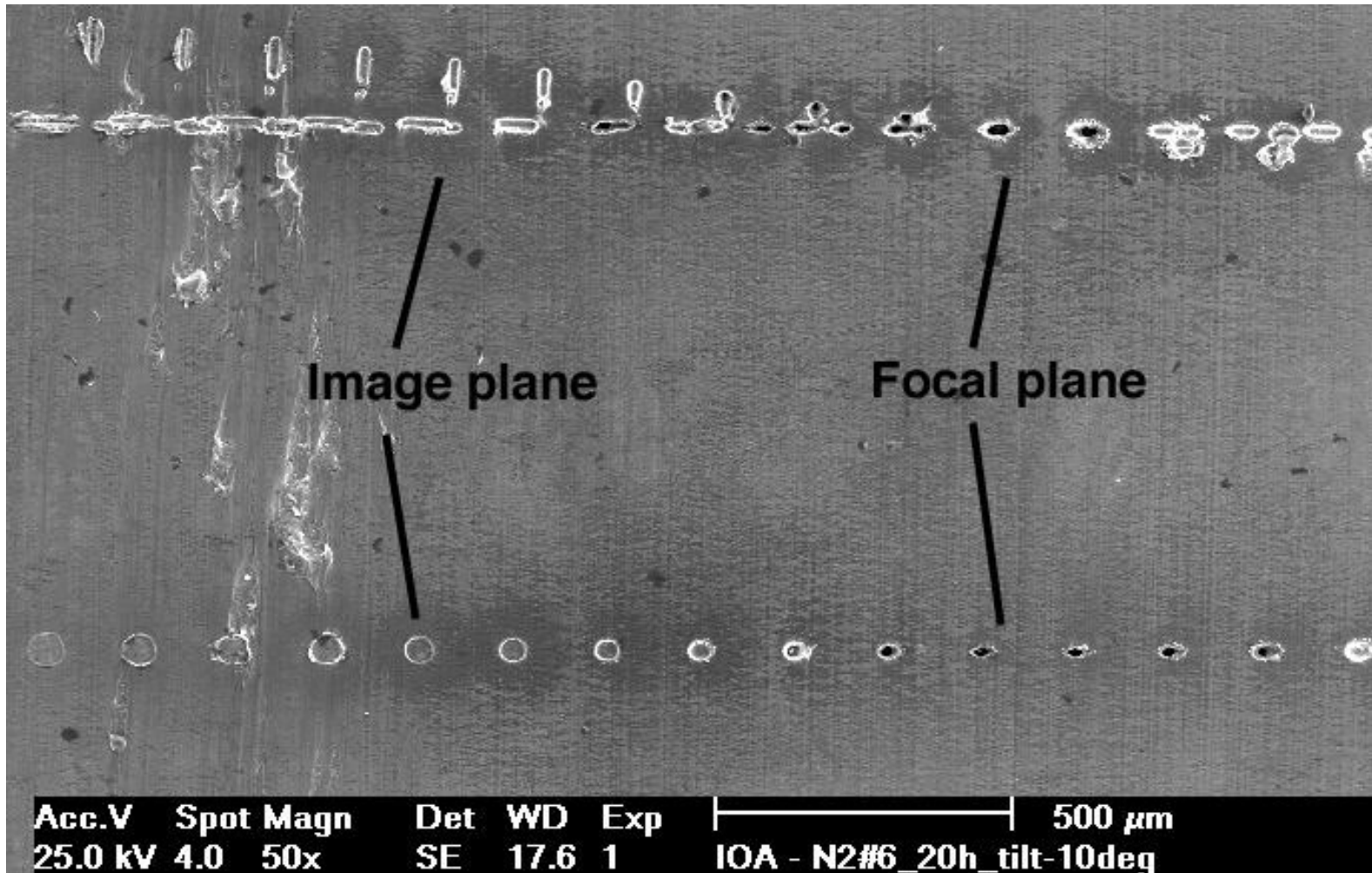
Theoretical optical resolution:

$$r = \frac{\lambda}{2 \cdot NA} = 241 \text{ nm}$$

# Schwarzschild objective: central obscuring



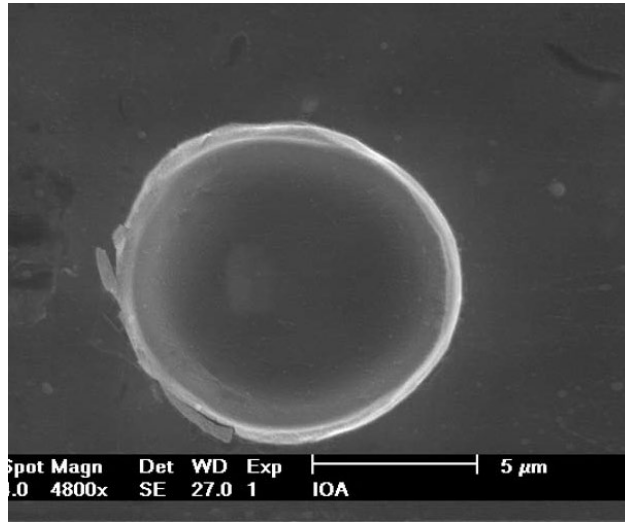
# Aluminium: Search for image / focal planes



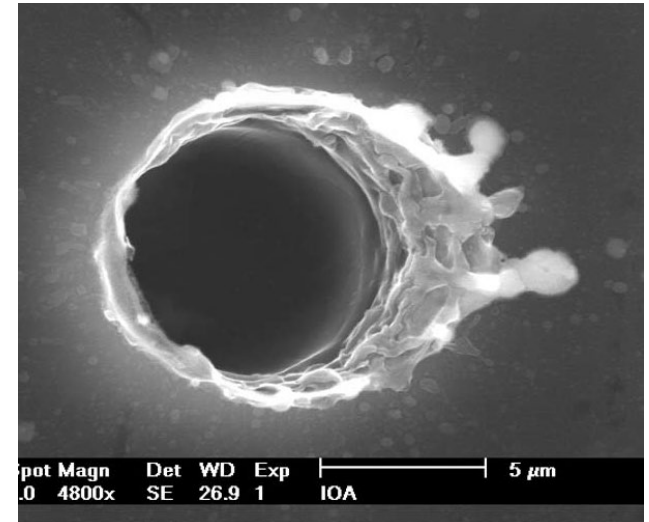
- Distance image-focal planes: 300 μm,  $F = 50 \text{ mJ/cm}^2$ , 5 pulses at 10 Hz

# Aluminium: variation of the number of pulses

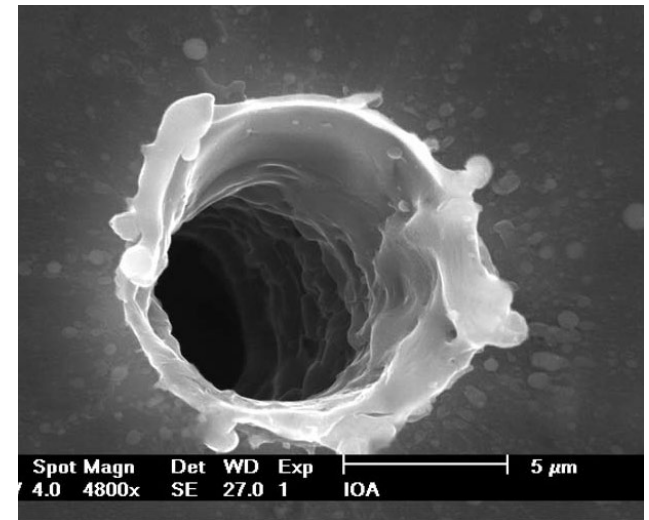
1 pulse



10 pulses



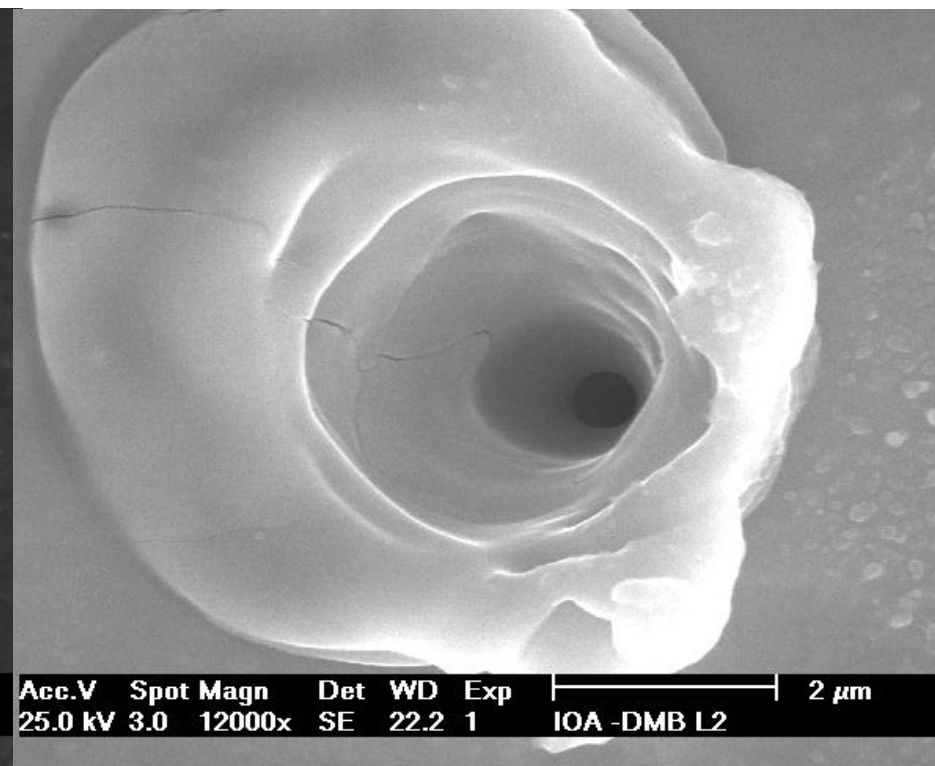
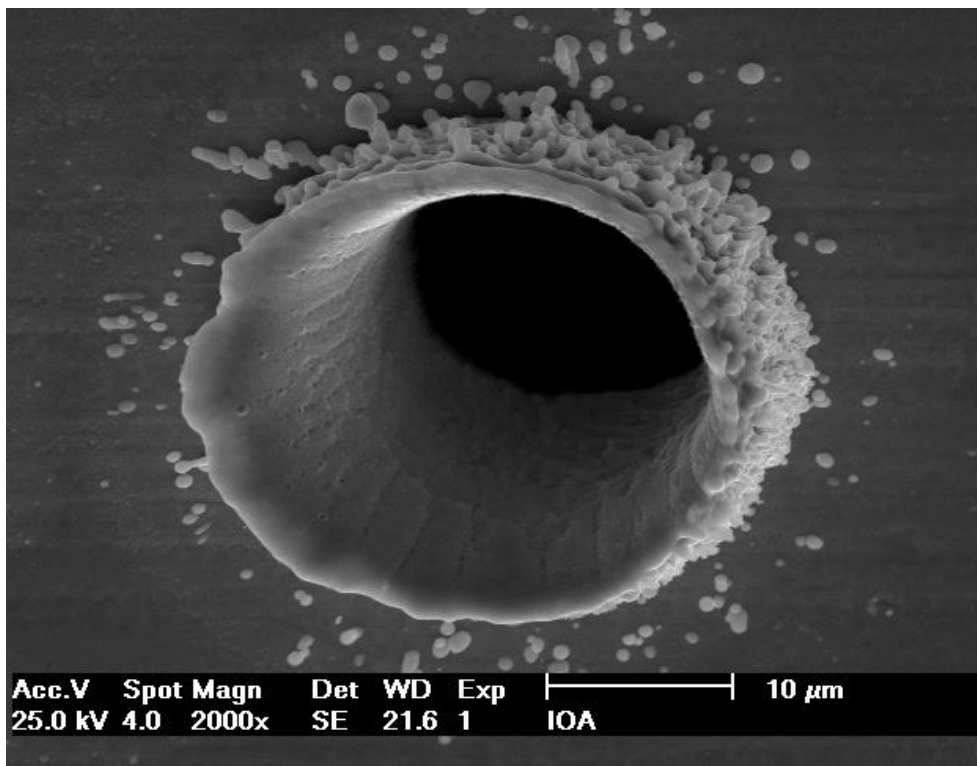
100 pulses



- Thickness : 20 μm,  $F = 15 \text{ mJ/cm}^2$
- Mask diameter:  $D = 215 \text{ μm}$

# Molybdenum: through-hole

- Thickness of the molybdenum:  $12.5\mu\text{m}$

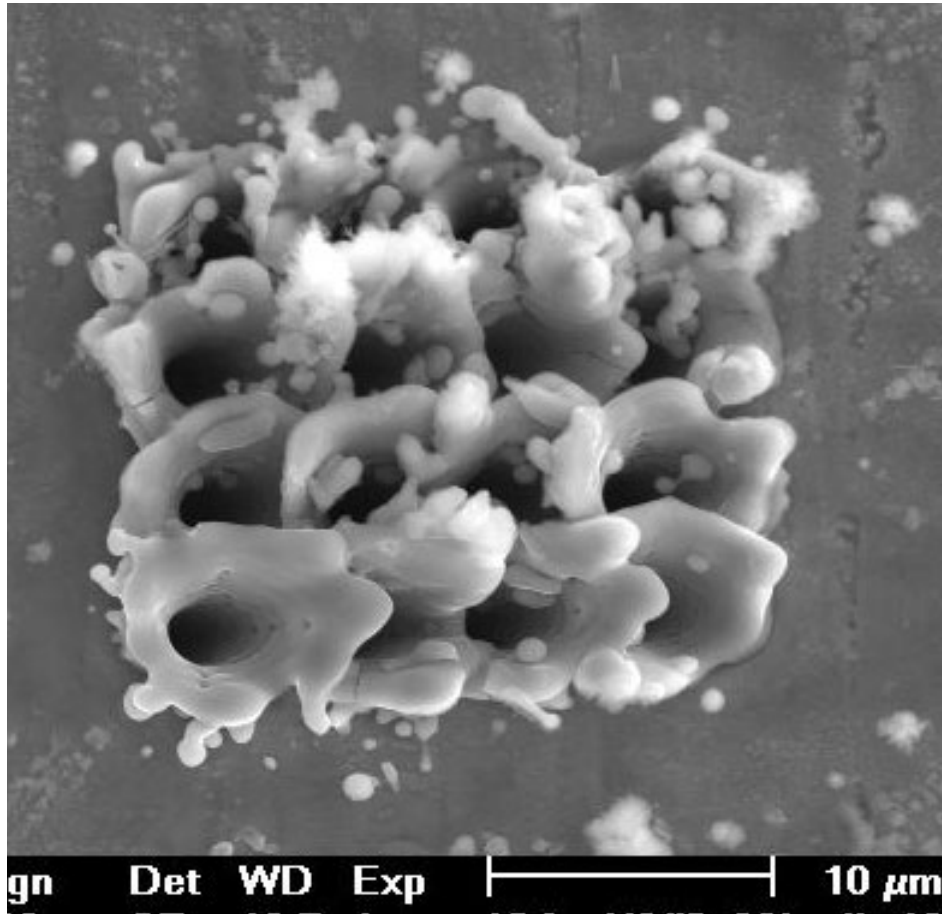


$250\text{ mJ/cm}^2$ , 40 pulses at 10 Hz

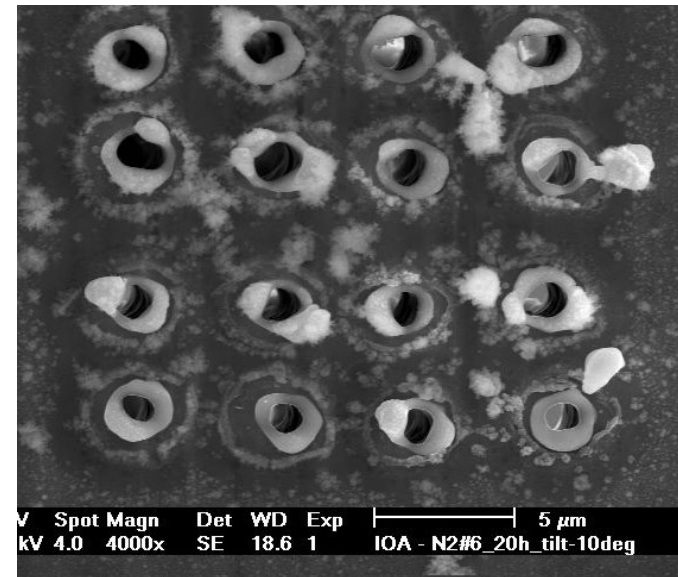
$25\text{ mJ/cm}^2$ , 2000 pulses at 40 Hz

# Molybdenum: multiple through holes

Entrance



Exit



$F = 25 \text{ mJ/cm}^2$

2000 pulses, 40 Hz

Mask diameter  $D = 215 \text{ μm}$

# Excimer Ablation conical structures

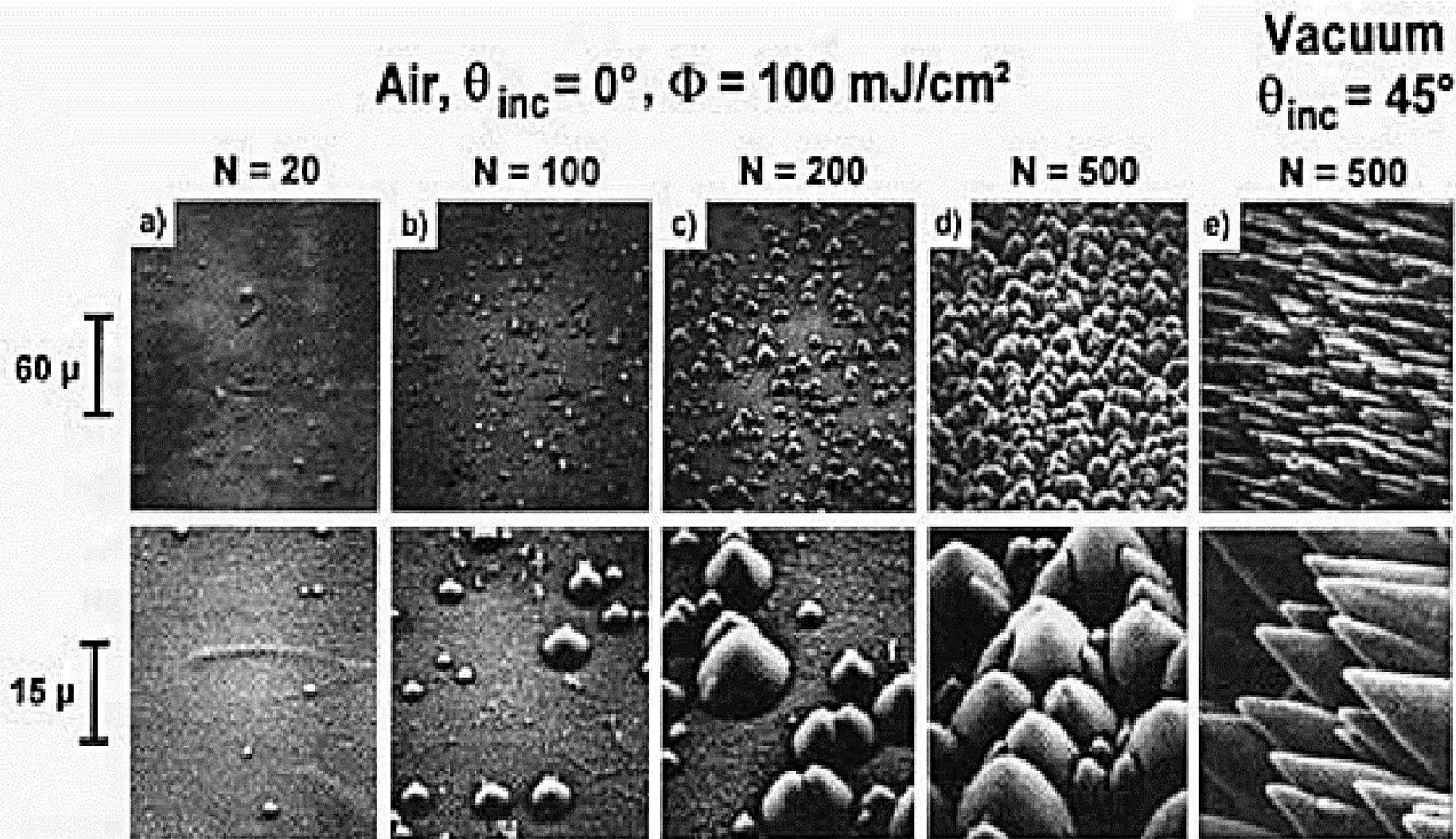


Fig. 28.4.4a-d. SEM photographs of polyimide ablated in air at  $\phi = 100 \text{ mJ/cm}^2$  for different numbers of pulses  $N$ . The laser beam was normally incident on the sample. (e) Same as (d) but irradiated in vacuum under  $\Theta = 45^\circ$  [Krajnovich and Vazquez 1993]

# Excimer Laser glass marking

## Static Excimer Ablation Process

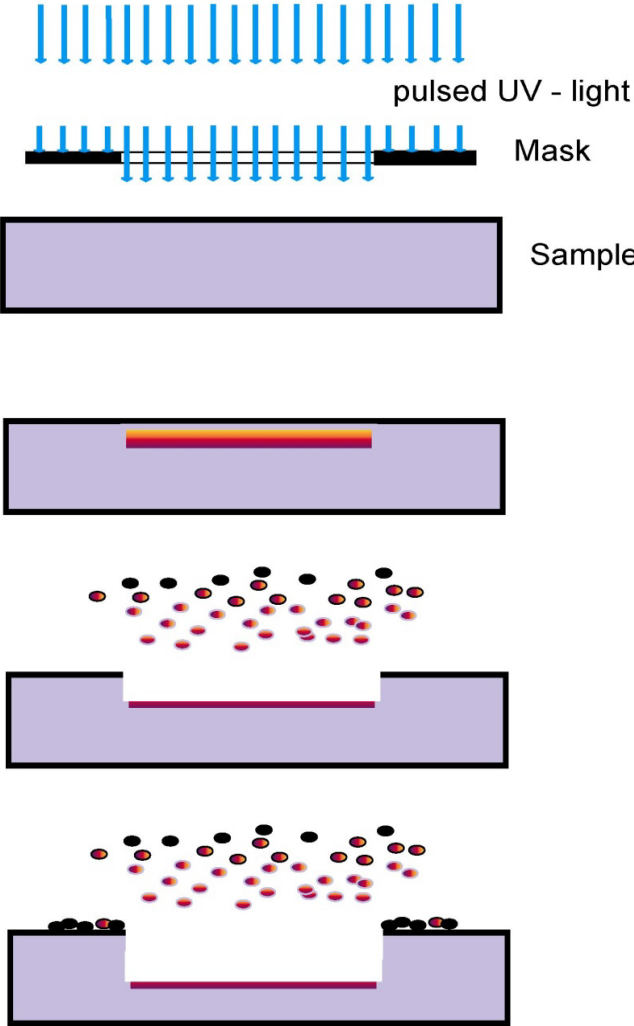


Abb. 4:  
Vergrößerung einer mit einem Excimerlaser  
markierten Glasoberfläche.

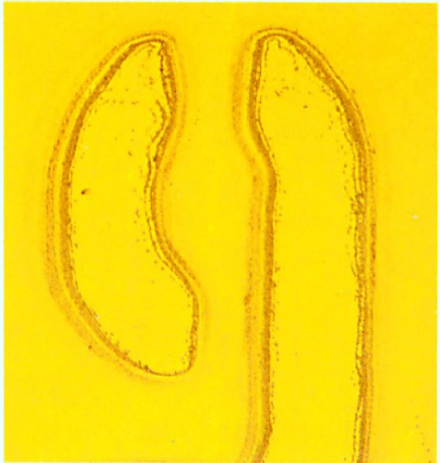
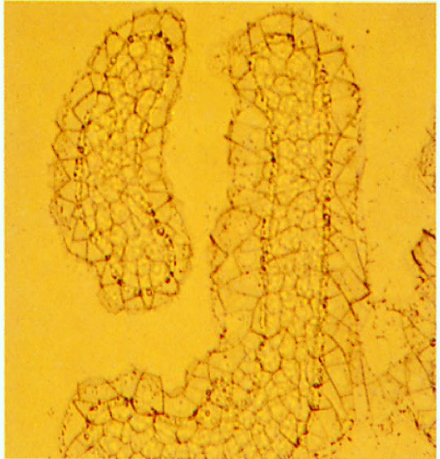


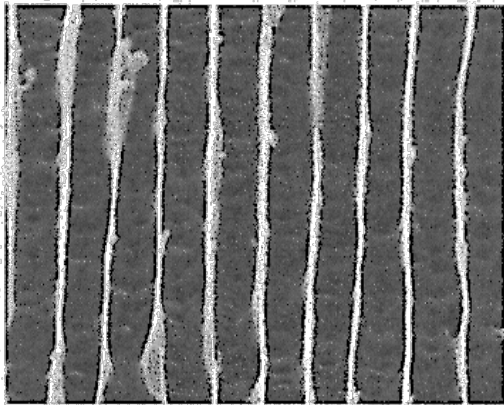
Abb. 5:  
Vergrößerung einer mit einem CO<sub>2</sub>-Laser  
markierten Glasoberfläche.



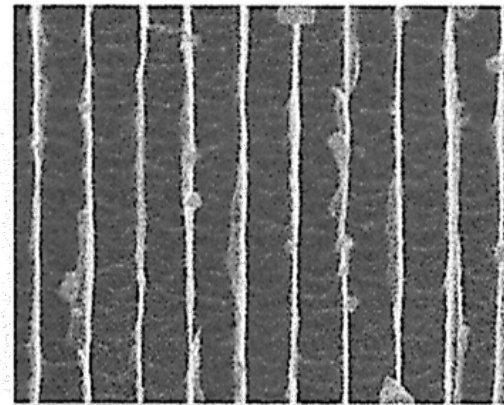
# Ablation quality pulse duration

**Material: Copper**

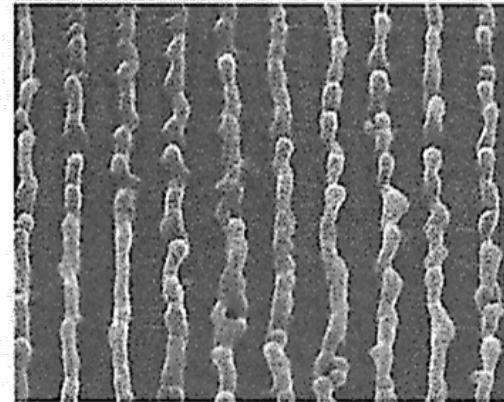
**Laser: 248 nm, 600 mJ/cm<sup>2</sup>, 1 pulse**



**0.5 ps**



**5 ps**

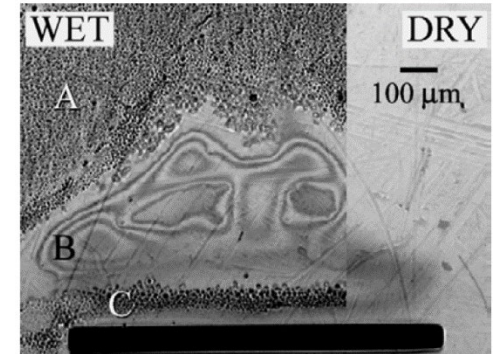
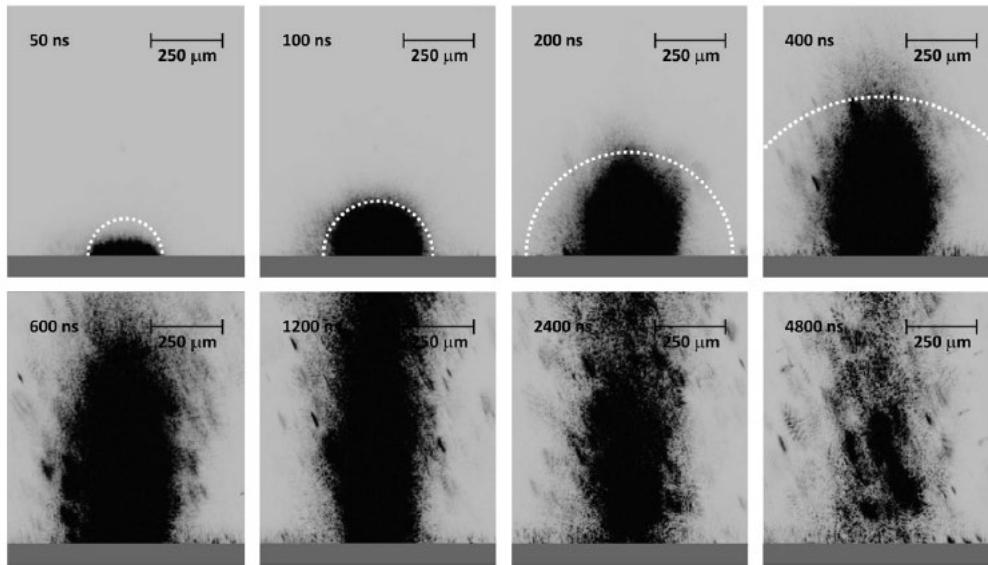


**50 ps**

**1 μm**



# Ultra short pulse ablation



Koch et al.  
Tom Lippert PSI  
– shadowgraphy  
- scatterometry

*J. Koch et al. / Spectrochimica Acta Part B 65 (2010) 943–949*

945

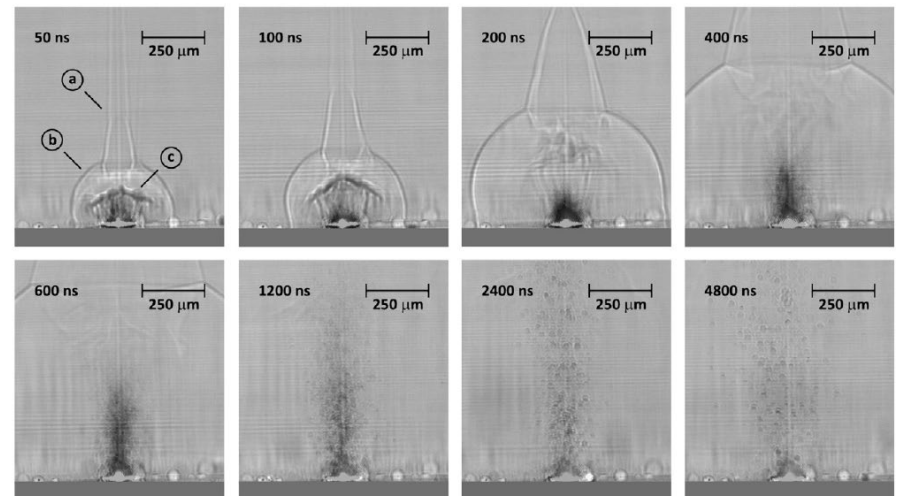


Fig. 1. Shadowgraphs acquired during fs-LA of  $\text{Li}_2\text{B}_4\text{O}_7$  in ambient air applying a fluence of  $10.8 \text{ J/cm}^2$ . Lower cases a, b, and c mark the positions of BSW, CSW-1, and CSW-2, respectively. Shockwave radii were systematically measured between their origin and the intersection of BSW and CSW-1.